

Amendments to the Claims

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims

Claim 1 (currently amended) A substrate for thin film formation in which a thin film comprises at least one or more materials selected from **the group consisting of** a gallium nitride, an indium nitride, and an aluminum nitride as the main **ingredient(s)**~~ingredients~~, and the substrate consists of a sintered compact which comprises an aluminum nitride as the main ingredient[[s]].

Claim 2 (currently amended) A substrate for thin film formation in which a thin film comprises at least one or more materials selected from **the group consisting of** a gallium nitride, an indium nitride, and an aluminum nitride as the main **ingredient(s)**~~ingredients~~, and the substrate consists of a sintered compact which comprises as the main ingredient[[s]] a ceramic material which has at least one of the crystal structures selected from a hexagonal system or a trigonal system.

Claim 3 (currently amended) A substrate for thin film formation in which a thin film comprises at least one or more materials selected from **the group consisting of** a gallium nitride, an indium nitride, and an aluminum nitride as the main **ingredient(s)**~~ingredients~~, and the substrate consists of a sintered compact which comprises a ceramic material as the main ingredient[[s]] and which has optical permeability.

Claims 4-25 (canceled)